



TIP105

PNP SILICON POWER DARLINGTON TRANSISTOR

- STMicroelectronics PREFERRED SALESTYPE
- INTEGRATED ANTIPARALLEL COLLECTOR-EMITTER DIODE
- h_{FE} CLASSIFICATION

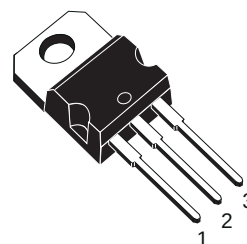
APPLICATIONS

- LINEAR AND SWITCHING INDUSTRIAL EQUIPMENT
- AUDIO POWER AMPLIFIER
- GENERAL POWER SWITCHING
- DC-AC CONVERTER
- EASY DRIVER FOR LOW VOLTAGE DC MOTOR

DESCRIPTION

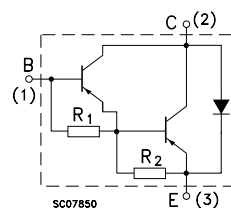
The TIP105 is a silicon Epitaxial-Base PNP transistor in monolithic Darlington configuration mounted in TO-220 plastic package intended for use in power linear and switching applications.

The preferred complementary NPN type is the TIP102.



TO-220

INTERNAL SCHEMATIC DIAGRAM



R_1 Typ. = 5 K Ω

R_2 Typ. = 150 Ω

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage ($I_E = 0$)	-60	V
V_{CEO}	Collector-Emitter Voltage ($I_B = 0$)	-60	V
V_{EBO}	Emitter-Base Voltage ($I_C = 0$)	-5	V
I_C	Collector Current	-8	A
I_{CM}	Collector Peak Current	-15	A
I_B	Base Current	-1	A
P_{tot}	Total Dissipation at $T_{case} \leq 25^\circ C$ $T_{amb} \leq 25^\circ C$	80 2	W W
T_{stg}	Storage Temperature	-65 to 150	$^\circ C$
T_j	Max. Operating Junction Temperature	150	$^\circ C$

THERMAL DATA

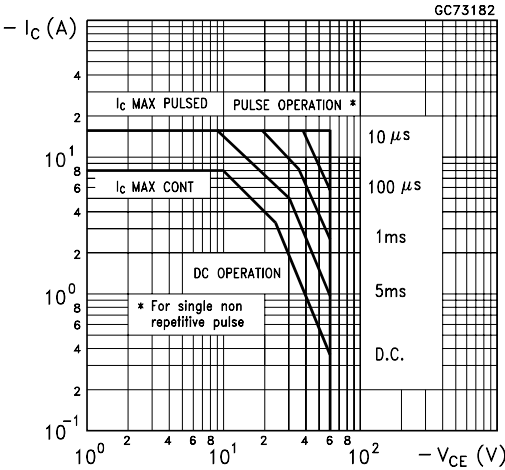
R _{thj-case}	Thermal Resistance Junction-case	Max	1.56	°C/W
R _{thj-amb}	Thermal Resistance Junction-ambient	Max	62.5	°C/W

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

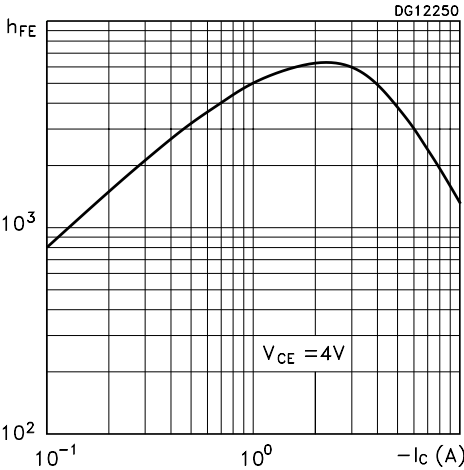
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I _{CEO}	Collector Cut-off Current (I _B = 0)	V _{CE} = -30 V			-50	μA
I _{CBO}	Collector Cut-off Current (I _E = 0)	V _{CE} = -60 V			-50	μA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = -5 V			-8	mA
V _{CEO(sus)} *	Collector-Emitter Sustaining Voltage (I _B = 0)	I _C = -30 mA	-60			V
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	I _C = -3 A I _C = -8 A			-2 -2.5	V V
V _{BE} *	Base-Emitter Voltage	I _C = -8 A V _{CE} = -4 V			-2.8	V
h _{FE} *	DC Current Gain	I _C = -3 A I _C = -8 A I _C = -3 A Group R Group O Group Y	V _{CE} = -4 V V _{CE} = -4 V V _{CE} = -4 V	2000 200 2000 4000 8000	18000 5000 9000 18000	
V _F *	Forward Voltage of Commutation Diode (I _B = 0)	I _F = - I _C = 10 A			-2.8	V

The product is pre-selected in DC current gain (Group R, Group O and Group Y). STMicroelectronics reserves the right to ship either groups according to production availability. Please contact your nearest STMicroelectronics sales office for delivery details.

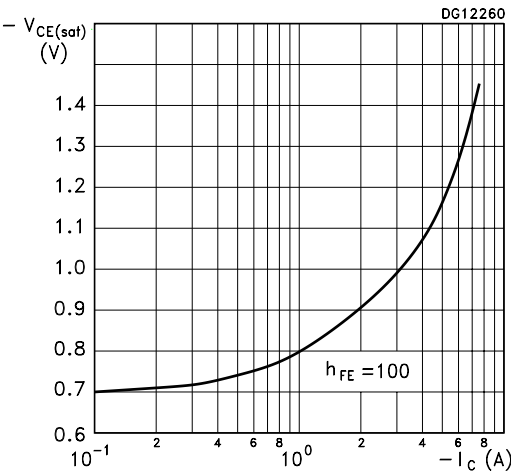
Safe Operating Area



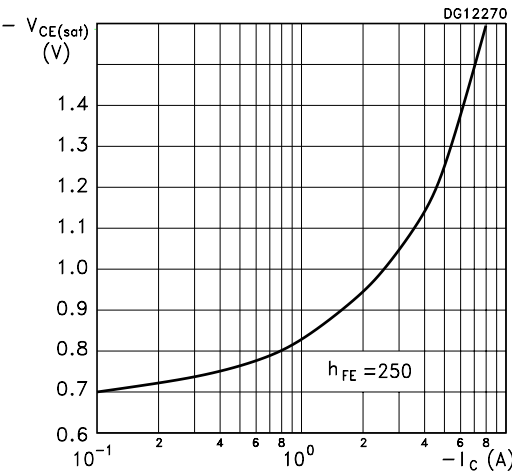
DC Current Gain



Collector-Emitter Saturation Voltage

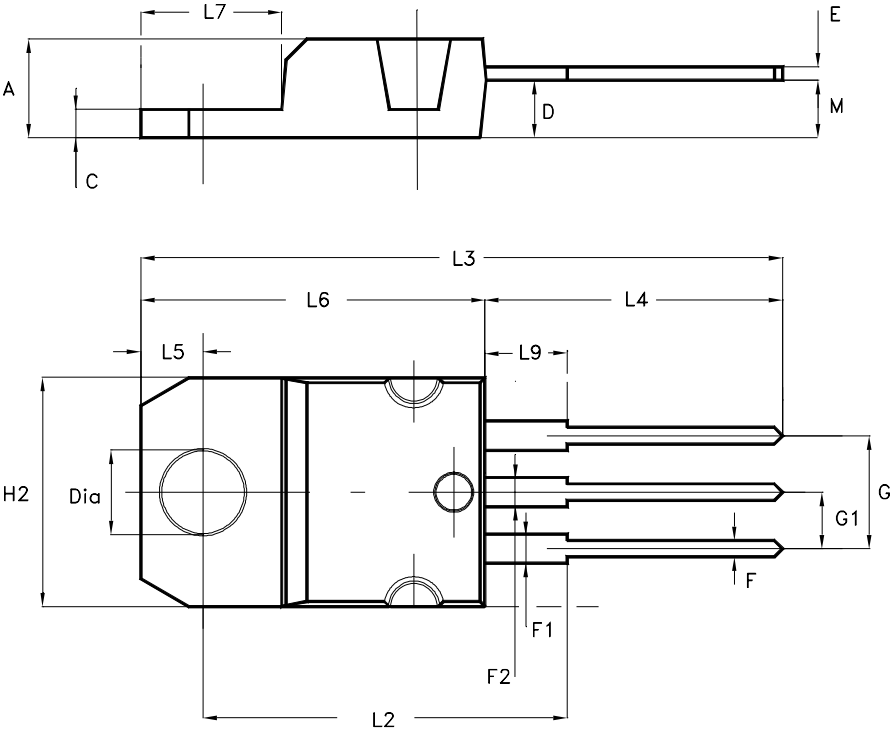


Collector-Emitter Saturation Voltage



TO-220 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.40		4.60	0.173		0.181
C	1.23		1.32	0.048		0.052
D	2.40		2.72	0.094		0.107
E	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.202
G1	2.40		2.70	0.094		0.106
H2	10.00		10.40	0.394		0.409
L2		16.40			0.645	
L4	13.00		14.00	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.20		6.60	0.244		0.260
L9	3.50		3.93	0.137		0.154
M		2.60			0.102	
DIA.	3.75		3.85	0.147		0.151



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